Angular Distribution of Electrons in Photoionization of Atoms Adsorbed on a Graphene Sheet

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Abstract
Within the framework of a model representing the potential of a graphene sheet $U(z)$ as an electro-neutral layer formed by smeared carbon atoms, the effect of this potential on spectral characteristics of atoms adsorbed on a graphene sheet has been studied. Since the distance between the adsorbed atom nucleus and sheet surface significantly exceeds the radii of inner atomic shells, the potential $U(z)$ makes influence on the continuum wave functions only. Their behavior in the upper semi-space ($z>0$) and in the lower one ($z<0$) where the adsorbed atom is located is defined by a jump of the logarithmic derivative of the wave function for $z=0$. The photoelectron angular distributions have been calculated for different mutual positions of the polarization vector $\mathbf{e}$ and the axis $Z$ normal to the sheet surface. It has been shown that the existence of the electron waves reflected from the potential $U(z)$ leads to evident asymmetry of the angular distribution relative to the plane $z=0$. The experimental observation of this effect is of great interest for photoelectron spectroscopy of atoms localized on graphene structures.

Keywords
Photoionization; Atom; Graphene; Angular Distribution

Introduction
The number of papers devoted to investigation of carbon nanostructures and their feasible applications has seen rapid increases [see Lehtinen et al. (2003), Saito et al. (1992), Ajayan (1999), Gerber et al. (2010), Xia et al. (2008), Mishra et al. (2012), Rangel & Seminario (2010) and references therein]. The atomic-scale understanding of the properties of the adatoms on a graphene sheet has become an essential part of such studies. The photoelectron spectroscopy is an effective precise method to investigate the electron structure of adatoms [Carlson (1975)]. The study of the interaction processes of ionizing radiation with single adatoms and surface structures on their basis will not only provide an answer to a number of the intriguing fundamental scientific problems of atomic, molecular physics and surface physics but also promote the development of surface-structures nano-engineering.

In this paper, the angular distribution of photoelectrons knocked-out from the deep subshells of atoms adsorbed on a graphene sheet was studied. Since we deal with physical adsorption when the adatom electronic structure is not subject to significant changes, the electronic subsystems of graphene sheet and adatom can be considered independently. The distance $d$ between the adsorbed atom nucleus and sheet surface is several atomic units (1.87Å [Lehtinen et al. (2003)]) and so it significantly exceeds the radii of inner atomic shells. That allows considering the wave functions of these shells with great accuracy as coinciding with the wave functions of the free atom. As far as the continuum wave functions are concerned, for near-threshold photoionization the wavelength of electrons produced in this process exceeds by far the bond lengths between the carbon atoms in the graphene sheet. This effectively obliterates the influence of the individual carbon atoms on the knocked-out low-energy photoelectron, thereby making the phenomenological potential $U(z)$ formed by the $z=0$-plane-smeared carbon atoms to be an excellent approximation. A matrix element of the optical transition is formed near the adatom nucleus where the potential of graphene sheet is equal to zero. Therefore the specific shape of the function $U(z)$ has no influence on the photoionization amplitude. This allows the real interaction potential $U(z)$ having a finite thickness to be replaced by a zero-range potential $U(z) = -A\delta(z)$ providing a necessary jump of the logarithmic derivative of the wave function at $z=0$.

A similar method based on the so-called Dirac-bubble-potential $U(r) = -A\delta(r-R)$ [Lohr et al. (1992)] for the $C_{60}$ fullerene shell was developed in [Baltenkov (1999),
Dolmatov et al. (2004), Baltenkov et al. (2010)] where this potential was used to describe the photoionization of endohedral atoms M@C60 as well. As a matter of fact, the M atom photoionization on a graphene sheet is the photoionization of the same atom M in the system M@C60 where the fullerene shell is expanded on a plane. The difference between the structures of graphene formed by 6-rings carbon atoms and the fullerene shell consisting of 5- and 6-rings plays no principal role.

Introducing the $\delta$-potential in the wave equation, *per se*, is a suitable mathematical way allowing replacement of the real interaction potential having a finite radius of action by a zero-range potential providing the necessary boundary conditions for the wave function of a particle moving in this potential. This idea originates from the classical paper on deuteron photodetachment [Bethe et al. (1935)]. This way allows avoiding arbitrariness for selecting the parameters of the potential well $U(z)$. This arbitrariness is restricted by a single parameter $A$ defined in experiment. It is evident that, as any model description, the $\delta$-potential model has a limited field of application. Within this model, it is impossible to consider the processes for which the electronic structure of the carbon nanostructures plays an essential role. Such processes are, in particular, those of C60 molecule photoionization. For correct description of this process for some photon energies, it is necessary to use the more sophisticated approaches for the fullerene electronic hull [McCune et al. (2009)].

The sequences taking into consideration of the atom photoionization processes the carbon nanostructures potentials $U(r) = -A\delta(r - R)$ and $U(z) = -A\delta(z)$ are principally different, which is understandable already at the qualitative level. In the first case, the spherically symmetric potential leads to radical changes in the photoionization *total cross sections* where the so-called confinement resonances discovered in the recent experiments [Kilcoyne et al. (2010)] appear. The amplitude of these resonances relate to the number of backscattered waves emitted by the nearby C atoms equidistantly located from the adatom nucleus. However, the question whether the changes in the shape of the angular distributions are observable and what their character is can be resolved by calculating the differential cross sections. In this paper, an answer to these questions can be achieved by considering the photoionization of atom near the graphene sheet within the framework of a simple model.

**Differential Photoionization Cross Section**

In the spherical coordinate system connected with the sheet surface, the axis Z is considered to be directed along the normal to the surface. The ionized atom M is placed in the lower semi-space (Fig. 1).

The spherical coordinates of the radiation polarization vector $e$ are $(\vartheta, \phi)$ and the coordinates of the vector of photoelectron momentum $k$ are $(k, \vartheta, \phi)$. It is known that the differential cross section of dipole photoionization of atom for linearly polarized light is determined by the cosine of the angle $\vartheta_{ek}$ (between the vectors $e$ and $k$) and has the general form (Bethe, H. 1933)

$$\frac{d\sigma}{d\Omega} = \frac{\sigma}{4\pi}[1 + \beta P_2(\cos \vartheta_{ek})]$$  \hspace{1cm} (1)
Here \( \sigma \) is the total photoionization cross section; \( \beta \) is the dipole asymmetry parameter. In the above-described coordinate system, the argument of the Legendre polynomial \( P_2(\cos \theta \phi) \) is represented as

\[
cos \theta \phi = \cos \theta \cos \phi + \sin \theta \sin \phi \cos (\phi - \phi_0)
\]

(2)

For the fixed coordinates of the radiation polarization vector \( \theta_0 \) and \( \phi_0 \), the shape of the electron angular distribution in the coordinate system connected with the sheet surface will be defined as the following function of spherical angles \( \theta \) and \( \phi \)

\[
F(\theta, \phi) = \frac{[1 + \beta P_2(\cos \theta \phi)]}{1 + \beta}.
\]

(3)

Since we are interested in the shape of the angular distribution only, this function was normalized so that it is equal to unity for \( \theta \phi = 0 \). The vector \( J = kF(\theta, \phi) \) is a flux of photoelectrons knocked-out by the ionizing atom (here and throughout the text the atomic system is a flux of photoelectrons knocked-out by the ionizing atom with unity intensity, a reflected wave with intensity \( |B|^2 \) and a wave passed over the potential well with intensity \( |1 + D|^2 \)). Because of the potential well with intensity \( |1 + D|^2 \). Because of the potential well with intensity \( |1 + D|^2 \).

The solution of Eq.(8) we write in the form (Flugge, S. 1971)

\[
\phi(z) = e^{ikz} + Be^{-ikz} \quad \text{for } z > 0,
\]

\[
\phi(z) = (1 + D)e^{ikz} \quad \text{for } z < 0.
\]

(9)

In the formulas (9) three waves are distinguished: an incident wave with unity intensity, a reflected wave with intensity \( |B|^2 \) and a wave passed over the potential well with intensity \( |1 + D|^2 \). Because of the continuum of the function \( \phi(z) \) at \( z = 0 \), the relation \( B = D \) for the scattering amplitudes was obtained. Integrating the equation (8) over \( z \) within the limits \( \pm \varepsilon \to 0 \), we obtain the equation connecting a jump of the logarithmic derivative of the wave function \( \Delta \phi(0) \) with the strength of the delta-potential:

\[
\Delta \phi(0) = \left[ \frac{\partial \phi}{\partial \zeta} \right]_{z = \varepsilon} - \left[ \frac{\partial \phi}{\partial \zeta} \right]_{z = -\varepsilon} \quad \text{for } \phi(0) = -2A.
\]

(10)

Substituting the functions (9) in Eq.(10), we obtain the following expression for the scattering amplitudes

\[
B = D = -\frac{A}{A + ik}\quad \text{for } z > 0.
\]

(11)

Owing to electron wave reflection from the potential plane, the electron flux vector has the following z-component in the lower semi-space

\[
j_z = F(\theta, \phi) |1 + |B|^2| k \cos \theta.
\]

(12)

and in the upper one

\[
j_z = F(\theta, \phi) |1 + D|^2 k \cos \theta = [1 - |B|^2] k \cos \theta.
\]

(13)

As far as the Cartesian components of the photoelectron flux \( j_x \) and \( j_y \) are concerned, they are undistorted by the potential \( U(z) \) and defined as before by the formulas (4). Finally, the formulas associating the function \( F(\theta, \phi) \) for the free atom with the angular distribution of electrons knocked out of the atom localized near the potential well \( U(z) \) in the Cartesian coordinates have the following form

\[
S_z = F(\theta, \phi) \sin \theta \cos \phi
\]

Graphene Sheet Effect

Until now, the above-given formulas relate to the free M atom. In the case of the ionization of adsorbed atom, the potential plane formed by the graphene sheet distorts the final-state wave function (5). Near the photoeffect threshold when the photoelectron wave length \( \lambda \) significantly exceeds the distance between the carbon atoms in the 6-rings forming the graphene sheet, its potential (by analogy with the Dirac-bubble-potential for C60 shell [Lohr et al. (1992)]) was regarded as a phenomenological potential \( U(z) = -A\delta(z) \) to simulate the smeared carbon atoms.

Within this model description, the wave function of photoelectron leaving the atomic residue will obey the following Schrödinger equation

\[
\Delta \psi_k + 2[E - U(z)]\psi_k = 0;
\]

\[
E = k^2/2 + \frac{k^2}{2} k^2 + k^2 z^2/2.
\]

(6)

The solution of this equation is written as

\[
\psi_k(r) = F(\theta, \phi)e^{ikz} \quad \text{for } z > 0,
\]

\[
\psi_k(r) = (1 + D)e^{ikz} \quad \text{for } z < 0.
\]

(7)

It is evident that for \( U(z) = 0 \) the function (7) coincides, as it should be, with the function (5). For the function \( \phi(z) \) we have the equation

\[
\frac{\partial^2 \phi}{\partial z^2} + [k^2 + 2A\delta(z)]\phi(z) = 0.
\]

(8)

The solution of Eq.(8) we write in the form (Flugge, S. 1971)

\[
\phi(z) = e^{ikz} + Be^{-ikz} \quad \text{for } z > 0,
\]

\[
\phi(z) = (1 + D)e^{ikz} \quad \text{for } z < 0.
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In the formulas (9) three waves are distinguished: an incident wave with unity intensity, a reflected wave with intensity \( |B|^2 \) and a wave passed over the potential well with intensity \( |1 + D|^2 \). Because of the continuum of the function \( \phi(z) \) at \( z = 0 \), the relation \( B = D \) for the scattering amplitudes was obtained. Integrating the equation (8) over \( z \) within the limits \( \pm \varepsilon \to 0 \), we obtain the equation connecting a jump of the logarithmic derivative of the wave function \( \Delta \phi(0) \) with the strength of the delta-potential:

\[
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\[
S_z = F(\theta, \phi) \sin \theta \cos \phi
\]
\[ S_y = F(\theta, \phi) \sin \theta \sin \phi, \]  
\[ S_z = F(\theta, \phi)[1 - |B|^2] \cos \theta, \] for the upper semi-space, 
\[ S_z = F(\theta, \phi)[1 + |B|^2] \cos \theta, \] for the lower semi-space.

The function \( |B|^2 \) in (14) has the form
\[ |B|^2 = \frac{A^2}{A^2 + k^2 \cos^2 \vartheta}. \]  
From (15) it follows that when the electron moves from the upper semi-space to the lower one or vice versa, i.e. at angles \( \vartheta = \pi/2 \) or \( 3\pi/2 \), the \( z \)-components of the function \( S_z \). Eq.(14) have the jump due to partial reflection of the electron flux from the potential well.

Let us investigate how the derived formulas are modified if the finite thickness of the graphene film is taken into consideration. The formulas (9) will have now the following form
\[ \phi(z) = e^{ibz} + Be^{-ibz} \quad \text{for} \quad z < b/2, \]
\[ \phi(z) = A_\xi(z) + C\zeta(z) \quad \text{for} \quad b/2 < z < b/2, \]
\[ \phi(z) = (1 + D)e^{ibz} \quad \text{for} \quad z > b/2. \]

Here \( A_\xi(z) + C\zeta(z) \) is the linear combination of the regular and irregular solutions of the Schrödinger equation inside the graphene sheet. Matching the logarithmic derivatives at the points \( z = \pm b/2 \) (here \( b \) is the effective film thickness shown in Fig. 1 by the dashed lines), the following expression for the amplitude of the reflected wave was obtained
\[ |B|^2 = \left| \frac{L_+ - L_-}{L_+ + L_-} \right|^2. \]  
Here \( L_+ \) and \( L_- \) are the logarithmic derivatives at the points \( z = \pm b/2 \), i.e. the two model parameters to be defined. Let us suppose that the potential \( U(z) \) is a squared well with the depth \( W \) and the thickness \( b \) that are connected with each other so that a bound state with energy \( I \) exists in this potential well. In the case of \( C_{60} \), it is generally accepted that the fullerene electronic hull has the thickness \( b=1.89 \) and the depth \( W =8.24 \) eV [Baltenkov et al. (2010)]. It is evident that for the graphene sheet these values of the parameters \( A, W \) and \( b \) should be considered as tentative. At the end of this section, we will analyze how the shape of photoelectron angular distribution are modified with variation of these parameters.

Let us consider the case of the s-states of the ionized atom. For them, the dipole asymmetry parameter is \( \beta = 2 \) and the function \( F(\theta, \phi) = \cos^2 \phi e^{ikz} \). The coordinate system is chosen so that the X-axis is in the same plane as the vectors \( e \) and \( Z \) where the intensity of photoelectron emission is maximal. In this coordinate system, the azimuth angle \( \phi \) in the formulas (14) is equal to zero and the photoelectron spectrum shape is defined by the \( x \)- and \( z \)-components of the function \( S \). The calculation results for the function \( S \) defining the photoelectron spectrum shape for two polar angles of the \( e \) vector \( \vartheta_e = \pi/2 \) and 0 are presented in Figs. 2 and 3. The angular distributions for free atom photoionization are presented in these figures and in the other ones for comparison.

In Fig. 2 the polar angle \( \vartheta_e \) is \( \vartheta_e = \pi/2 \) and the

\[ 1 - |B|^2 = |1 + D|^2. \]

As before, the formulas (14) describe the shape of the photoelectron angular distribution and they will be used for numerical calculations.

### Numerical Calculations

#### S-atomic State

For the strength of the delta-potential \( A \) defining the scattering amplitude (11) to be evaluated, it was assumed that the potential of the graphene sheet \( U(z) \) is similar to a plane-expanded potential of the fullerene \( C_{60} \) shell. Based on this assumption, the parameter \( A \) can be found from the experimental data on the fullerene radius \( R \) and the electron affinity energy \( l \). According to [Baltenkov (1999)],

\[ A = \beta(1 + \coth \beta R)/2, \]  
where the parameter \( \beta \) is \( \beta = (2I)^{1/2} \). For \( I = 2.65 \) eV and \( R = 6.639 \) [Tossati et al. (1994)] the value of the potential strength \( A \) is \( A=0.441 \).

This value corresponds to spherical potential well of the squared profile with the depth \( W \) and the thickness \( b \) that are connected with each other so that a bound state with energy \( I \) exists in this potential well. In the case of \( C_{60} \), it is generally accepted that the fullerene electronic hull has the thickness \( b=1.89 \) and the depth \( W =8.24 \) eV [Baltenkov et al. (2010)]. It is evident that for the graphene sheet these values of the parameters \( A, W \) and \( b \) should be considered as tentative. At the end of this section, we will analyze how the shape of photoelectron angular distribution are modified with variation of these parameters.

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In Fig. 2 the polar angle \( \vartheta_e \) is \( \vartheta_e = \pi/2 \) and the
function $F(\theta, \phi)$ is $F(\theta, \phi) = \sin^2 \theta$. This function is not equal to zero at the angles $\theta = \pi / 2$ and $3\pi / 2$ and at these points the jumps of the function $S_z$ manifest themselves in the explicit form. The upper spectrum part corresponding to the angular distribution of photoelectrons passing through the potential plane is evidently less than the lower one. With the rise in photoelectron kinetic energy $\varepsilon$ the reflected wave amplitude (15) decreases and the spectrum shape for adatoms is transformed into that corresponding to the free atom.

The curves for the angle $\theta_z = 0$ for which the function $F(\theta, \phi)$ is $F(\theta, \phi) = \cos^2 \theta$ are presented in Fig. 3. For the angles $\theta = \pi / 2$ and $3\pi / 2$ the function $F(\theta, \phi)$ vanishes and so the jumps in $S_z$ are not explicit. The upper spectrum part corresponding to the angular distribution of photoelectrons passing through the potential plane, as in Fig. 2, is vividly less than the lower one. For $\| Z \|$ the spectrum shapes are independent of the azimuth angle $\phi$ and the 3D-pictures of the photoelectron angular distribution are the figures formed by rotating the curves around the $Z$-axis. For all the polar angles of the vector $e$, the picture of spectrum transformation due to the potential $U(z)$ is qualitatively the same: electron wave reflection leads to enhancing the flux to the lower semi-space and weakening to the upper one. With the rise in photoelectron kinetic energy $\varepsilon$ the adatom spectra are transformed into those corresponding to the free atom.

Let us compare the amplitudes of electron wave reflection in the models of zero and finite thicknesses of the potential well $U(z)$. In the $\delta$-potential model the reflection coefficient is defined by the formula (15). The value of the potential strength $A$ in (15) corresponds to potential well with the above defined parameters $W$ and $b$. Another several pairs of the parameters $W$ and $b$ meeting the condition of bound state existence in the well [Baltenkov et al. (2010)] were taken into consideration. The comparison results of the reflection amplitudes (15) and (19) with these parameters are presented in Fig. 4. It is seen that the narrower and deeper the potential well is, the wider the electron energy range where the behavior of the reflection amplitudes in the both models is similar.
delta-potential $A$ for fixed electron energy ($k=0.6$). With the rise in the parameter $A$, the reflected wave amplitude (15) goes to unity and the photoelectron flux is almost totally reflected by the potential plane to the lower semi-space.

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Non-zero Orbital Moments

The photoelectron angular distribution for the atomic shells with nonzero orbital moments is characterized by the dipole asymmetry parameter $\beta$ changeable within the range $-1 \leq \beta \leq 2$. It is possible to see the evolution of the photoelectron spectrum shape for the parameter $\beta$ in the interval $-0.5 \leq \beta \leq 1.0$ in Fig. 6. The polarization vector $\mathbf{e}$ here is parallel to the $Z$-axis. The calculations were performed for two values of electron momentum $k=0.6$ and $k=1.0$. As before, with the rise in electron energy $\varepsilon$ the adatom spectra are transformed into those corresponding to the free atom. The electron angular distribution for parameter $\beta = 0$ corresponds, per se, to the picture of the light intensity of the isotropic source (candle) located near semitransparent mirror when an observer is far from it at the distance significantly exceeding $d$ and so the light source and its reflection in mirror are perceived as a point source of light.

As it follows from the figures, the existence of the electron waves reflected from the graphene sheet potential $U(z)$ leads to quite observable asymmetry in the angular distribution relative to the plane $z=0$; the less the photoelectron kinetic energy $\varepsilon$ is, the more pronounced the effect is.

![Fig. 5. The angular distributions of photoelectrons knocked out of the s-atomic subshells for different values of the parameter $A$ and for fixed electron momentums $k=0.6$. The polarization vector is $\mathbf{e} \parallel Z$. Dash-dot-dot black line – free atom; solid red line – atom + graphene sheet for $A=0.441$; dashed blue line – adatom for $A=1.0$; dot green line – adatom for $A=2.0$.](image)

![Fig. 6. The angular distributions of photoelectrons knocked out of the atomic subshells with nonzero orbital moments for different dipole asymmetry parameters $\beta$ and different electron kinetic energy $\varepsilon = k^2/2$. The polarization vector is $\mathbf{e} \parallel Z$. Dash-dot black lines – free atom; solid red lines – atom + graphene sheet for $k=0.6$; dash blue lines – atom + graphene sheet for $k=1.0$. The 3D-pictures of the photoelectron angular distribution are the figures formed by the curves rotation around the Z-axis.](image)
For $k=0.6$ the electron wave length is $\lambda = 2\pi / k \approx 10$ while the distance between the carbon atoms in graphene is $a=1.42\text{Å}=2.68$ [Abergel et al. (2009)]. For these electron wave lengths $\lambda >> a$ the developed model is parametrically justified The experimental observation of this new physical effect is of great interest for photoelectron spectroscopy of atoms localized on graphene structures.

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